

SEMITOP<sup>®</sup> 3

# 3-phase bridge rectifier + brake chopper

#### SK 55 DGL 126

Preliminary Data

#### Features

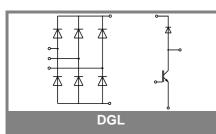
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded alumium oxide ceramic (DCB)
- Trench IGBT technology
- CAL Technology FWD

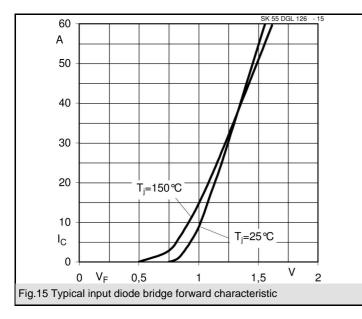
#### **Typical Applications\***

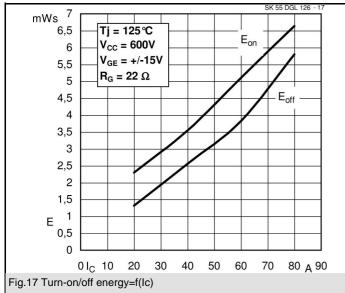
Rectifier

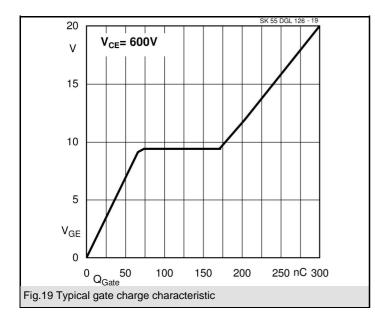
Absolute Maximum Ratings		T <sub>s</sub> = 25°C	$T_s$ = 25°C, unless otherwise specified						
Symbol	Conditions		Values						
IGBT - Chopper									
V <sub>CES</sub>			1200		V				
I <sub>C</sub>	T <sub>s</sub> = 25 (80) °C		40 (32)		А				
I <sub>CRM</sub>	$I_{CRM} = 2 \times I_{Cnom}, t_p = 1 \text{ ms}$		70		А				
V <sub>GES</sub>			±20		V				
Т <sub>ј</sub>			-40 +150		°C				
Diode - Chopper									
I <sub>F</sub>	T <sub>s</sub> = 25 (80) °C		45 (35)						
I <sub>FRM</sub>	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$		100		А				
Т <sub>ј</sub>			-40 +150		°C				
Rectifier		·							
V <sub>RRM</sub>			1600		V				
I <sub>D</sub>	T <sub>s</sub> = 80 °C		55		А				
I <sub>FSM</sub> / I <sub>TSM</sub>	t <sub>p</sub> = 10 ms , sin 180 ° ,T <sub>j</sub> = 25 °C		370						
l <sup>2</sup> t	t <sub>p</sub> = 10 ms , sin 180 ° ,T <sub>j</sub> = 25 °C		685		A²s				
Т <sub>ј</sub>			-40 +150		°C				
T <sub>sol</sub>	Terminals, 10s		260 ° -40 +125 °						
T <sub>stg</sub>			-40 +125						
V <sub>isol</sub>	AC, 1 min. / 1s		2500 / 3000 V						
Characteristics		T <sub>s</sub> = 25°C	$T_s$ = 25°C, unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units				
IGBT - CI	hopper								
V <sub>CEsat</sub>	I <sub>C</sub> = 35 A, T <sub>i</sub> = () °C		1,7 (2)	2,1	V				
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}, I_{C} = 1,5 \text{ mA}$	5	5,8	6,5	V				
V <sub>CE(TO)</sub>	T <sub>j</sub> = 25 °C (125) °C		1 (0,9)	1,2	V				
r <sub>T</sub>	T <sub>i</sub> = 25 °C (125) °C		20 (31)	26	mΩ				

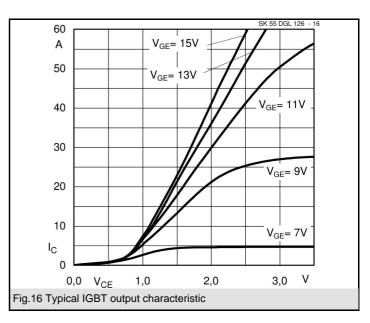
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}, I_{C} = 1,5 \text{ mA}$	5	5,8	6,5	V			
V <sub>CE(TO)</sub>	T <sub>i</sub> = 25 °C (125) °C		1 (0,9)	1,2	V			
r <sub>T</sub>	T <sub>i</sub> = 25 °C (125) °C		20 (31)	26	mΩ			
C <sub>ies</sub>	V <sub>CE</sub> = 25 V <sub>GE</sub> = 0 V, f = 1 MHz		2,4		nF			
C <sub>oes</sub>	V <sub>CE</sub> = 25 V <sub>GE</sub> = 0 V, f = 1 MHz		0,5		nF			
C <sub>res</sub>	V <sub>CE</sub> = 25 V <sub>GE</sub> = 0 V, f = 1 MHz		0,4		nF			
R <sub>th(j-s)</sub>	per IGBT			1,05	K/W			
t <sub>d(on)</sub>	under following conditions		85		ns			
tr	$V_{CC}$ = 600 V, $V_{GE}$ = ± 15 V		30		ns			
t <sub>d(off)</sub>	I <sub>C</sub> = 30 A, T <sub>j</sub> = °C		430		ns			
t <sub>f</sub>	$R_{Gon} = R_{Goff} = 22 \Omega$		90		ns			
E <sub>on</sub>	inductive load		4,6		mJ			
E <sub>off</sub>			4,3		mJ			
Diode - C	hopper							
$V_F = V_{EC}$	I <sub>F</sub> = 45 A, T <sub>i</sub> = () °C		1,5 (1,5)	1,77 (1,77)	V			
V <sub>(TO)</sub>	$T_{i} = C (125) C$		(0,92)		V			
r <sub>T</sub>	$T_{i} = °C (125) °C$		(13,4)		mΩ			
R <sub>th(j-s)</sub>	per diode			1,2	K/W			
I <sub>RRM</sub>	under following conditions		30		А			
Q <sub>rr</sub>	I <sub>F</sub> = 50 A, V <sub>R</sub> = 600 V		10		μC			
Err	V <sub>GE</sub> = 0 V, T <sub>i</sub> = °C				mJ			
	di <sub>F/dt</sub> = 500 Å/µs							
Diode rec	tifier							
V <sub>F</sub>	I <sub>F</sub> = 25 A, T <sub>j</sub> = () °C		-	1,25	V			
V <sub>(TO)</sub>	T <sub>i</sub> = 150 °C		0,8		V			
r <sub>T</sub>	T <sub>j</sub> = 150 °C		13		mΩ			
R <sub>th(j-s)</sub>	per diode		2		K/W			
	tur sensor							
R <sub>ts</sub>	%, T <sub>r</sub> = () °C		()		Ω			
Mechanic	Mechanical data							
w			30		g			
M <sub>s</sub>	Mounting torque			2,5	Nm			

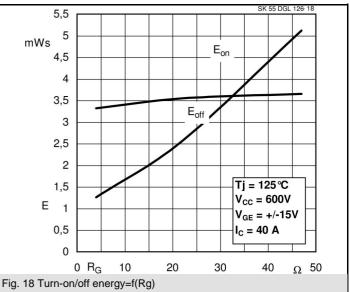


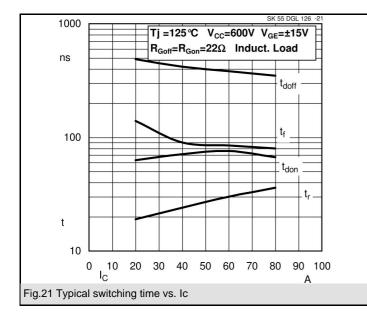


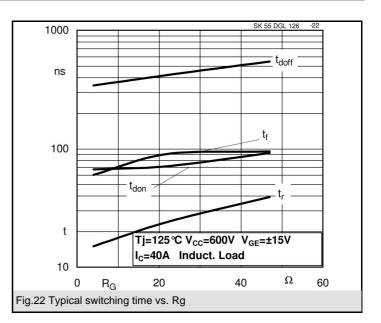


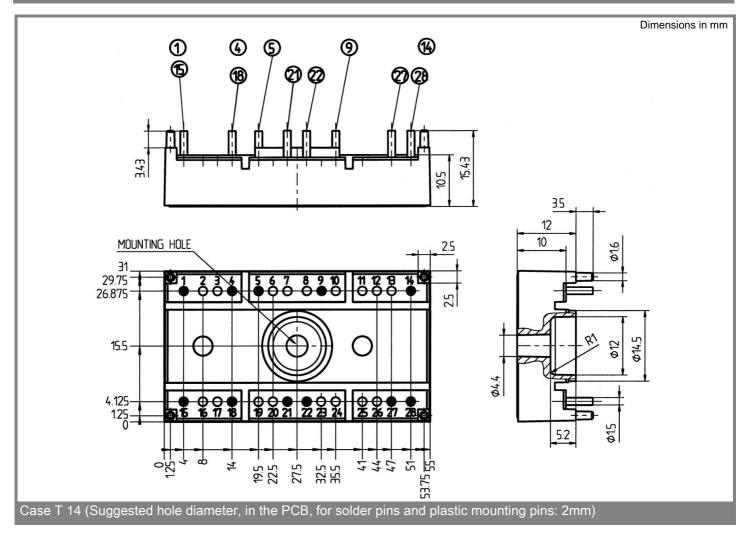


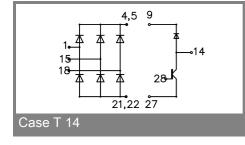












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.